

# **Excellent Integrated System Limited**

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Vishay/Siliconix SIP32458DB-T2-GE1

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Vishay Siliconix

FREE

### 20 m $\Omega$ , Slew Rate Controlled Load Switch in WCSP6

#### **DESCRIPTION**

SiP32458 and SiP32459 are slew rate controlled integrated high side load switches that operate in the input voltage range from 1.5 V to 5.5 V.

SiP32458 and SiP32459 are of P-channel MOSFET switching element with integrated gate pump that provides  $20 \text{ m}\Omega$  switch on resistance over a wide input voltage range.

These devices have low voltage logic control threshold that can interface with low voltage control I/O directly without extra level shift or driver. A 2.8 M $\Omega$  pull-down resistor is integrated at logic control EN pin.

The slow slew rate of SiP32458 and SiP32459 in the range of 3 ms limits the in-rush current and minimized the switching noise.

The SiP32458 features a reverse current blocking capability while the SiP32459 features an integrated output discharge switch

Both SIP32458 and SiP32459 are available in compact wafer level WCSP package, WCSP6 1 mm x 1.5 mm with 0.5 mm pitch.

#### **FEATURES**

- Low input voltage, 1.5 V to 5.5 V
- Low R<sub>ON</sub>, 20 mΩ typical at 5 V
- · Slew rate control
- Low logic control
- Reverse current blocking when disabled (SiP32458, without output discharge switch)
- Integrated output discharge switch (SiP32459 only)
- · Integrated pull down resistor at EN pin
- 6 bumps WCSP package
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?9991"><u>www.vishay.com/doc?9991</u></a>

#### **APPLICATIONS**

- · Battery operated devices
- Smart phones
- · GPS and PMP
- Computer
- · Medical and healthcare equipment
- · Industrial and instrument
- · Cellular phones and portable media players
- Game console

#### TYPICAL APPLICATION CIRCUIT

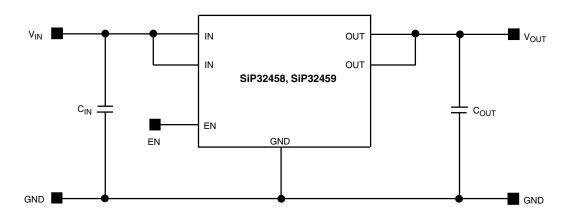


Figure 1 - SiP32458 and SiP32459 Typical Application Circuit

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Datasheet of SIP32458DB-T2-GE1 - IC SW W/CTRL SLEW RATE WCSP6

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## SiP32458, SiP32459

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ORDERING INFORMATION						
Temperature Range	Package	Marking	Part Number			
- 40 °C to 85 °C	WCSP: 6 Bumps (2 x 3, 0.5 mm pitch,	AA	SiP32458DB-T2-GE1			
	250 μm bump height, 1.5 mm x 1 mm die size)	AB	SiP32459DB-T2-GE1			

Note:

GE1 denotes halogen-free and RoHS compliant

Parameter	Limit	Unit	
Supply Input Voltage (V <sub>IN</sub> )	- 0.3 to 6		
Enable Input Voltage (V <sub>EN</sub> )	- 0.3 to 6	V	
Output Voltage (V <sub>OUT</sub> )	- 0.3 to 6		
Maximum Continuous Switch Current (I <sub>max.</sub> )	3	^	
Maximum Pulsed Current (I <sub>DM</sub> ) V <sub>IN</sub> (Pulsed at 1 ms, 10 % Duty Cycle)	6	_ A	
ESD Rating (HBM)	4000	V	
Junction Temperature (T <sub>J</sub> )	- 40 to 150	°C	
Thermal Resistance $(\theta_{JA})^a$	110	°C/W	
Power Dissipation (P <sub>D</sub> ) <sup>a</sup>	500	mW	

#### Notes:

- a. Device mounted with all bumps soldered to PC board.
- b. Derate 9.1 mW/°C above T<sub>A</sub> = 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE					
Parameter	Limit	Unit			
Input Voltage Range (V <sub>IN</sub> )	1.5 to 5.5	V			
Operating Junction Temperature Range	- 40 to 125	°C			





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Parameter	Symbol	Test Conditions Unless Specified $V_{IN} = 1.5 \text{ V}$ to 5.5 V, $T_A = -40 ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (Typical values are at $V_{IN} = 4.5 \text{V}$ , $T_A = 25 ^{\circ}\text{C}$ )		Limits			Unit
i didilictei	Gyillboi			Min. <sup>a</sup>	Typ. <sup>b</sup>	Max. <sup>a</sup>	1
Operating Voltage <sup>c</sup>	V <sub>IN</sub>			1.5	-	5.5	V
Quiescent Current	ΙQ	$V_{EN} = V_{I}$	N, OUT = open	-	4.2	9.5	
Off Supply Current	I <sub>Q(off)</sub>	SiP32458 SiP32459	EN = GND, OUT = open	-	-	1 10	
Off Switch Current	I <sub>DS(off)</sub>		ND, OUT = 0 V		-	10	μΑ
Reverse Blocking Current	I <sub>RB</sub>	V <sub>OUT</sub> = 2.5 V, V <sub>IN</sub> = 0.75 V, V <sub>EN</sub> = 0 V (SiP32458 only)		-	-	10	1
		V <sub>IN</sub> = 1.5 V, I <sub>L</sub> = 500 mA, T <sub>A</sub> = 25 °C		-	30	36	mΩ
On Basistana	R <sub>DS(on)</sub>	$V_{IN}$ = 1.8 V, $I_L$ = 500 mA, $T_A$ = 25 °C		-	26	32	
On-Resistance		$V_{IN} = 3.3 \text{ V, } I_L = 500 \text{ mA, } T_A = 25 ^{\circ}\text{C}$		-	20	26	
		V <sub>IN</sub> = 5 V, I <sub>L</sub>	-	20	26		
On-Resistance TempCoefficient	TC <sub>RDS</sub>			-	2820	-	ppm/°C
Output Pulldown Resistance	R <sub>PD</sub>	$V_{IN} = 3.3 \text{ V}, I_{OUT} = 5 \text{ mA}, V_{EN} = 0 \text{ V}$ (SiP32459 only)		-	70	-	Ω
EN Input Low Voltage <sup>c</sup>	V <sub>IL</sub>	V <sub>II</sub>	<sub>N</sub> = 1.5 V	-	-	0.4	V
EN Input High Voltage <sup>c</sup>	V <sub>IH</sub>	V <sub>IN</sub> = 5.5 V		1	-	-	V
EN Innut Lockego	_	V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V		-	-	1	μА
EN Input Leakage	I <sub>EN</sub>	$V_{IN} = 5.5 \text{ V}, V_{EN} = 1.2 \text{ V}$		-	0.44	1	
EN Pull Down Resistor	R <sub>EN</sub>	V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 1.2 V		-	2.8	-	MΩ
Output Turn-On Delay Time	t <sub>d(on)</sub>	$V_{IN}$ = 4.5 V, $R_{LOAD}$ = 5 Ω, $C_L$ = 100 μF, $T_A$ = 25 °C		-	0.5	-	me
Output Turn-On Rise Time	t <sub>r</sub>			-	3	-	ms
Output Turn-Off Delay Time	t <sub>d(off)</sub>			-	18	-	μs

- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
- b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- c. For V<sub>IN</sub> outside this range consult typical EN threshold curve.

#### **PIN CONFIGURATION**

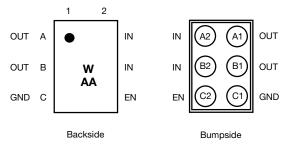


Figure 2 - WCSP 2 x 3 Package

PIN DESCRIPTION					
Pin Number	Name	Function			
A1, B1	OUT	These are the output pins of the switch			
C1	GND	Ground connection			
A2, B2	IN	These are input pins of the switch			
C2	EN	Enable input			

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#### **BLOCK DIAGRAM**



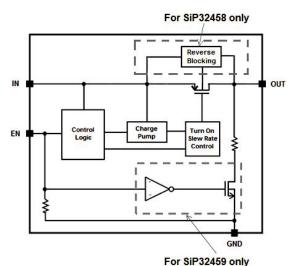


Figure 3 - Functional Block Diagram

#### TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

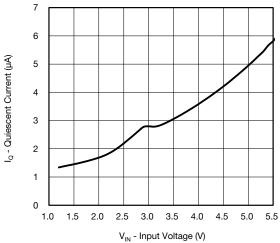


Figure 4 - Quiescent Current vs. Input Voltage

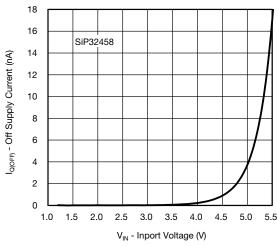


Figure 5 - Off Supply Current vs. Input Voltage

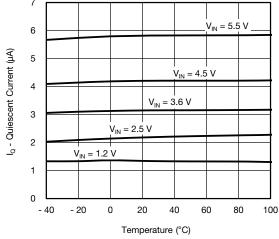


Figure 6 - Quiescent Current vs. Temperature

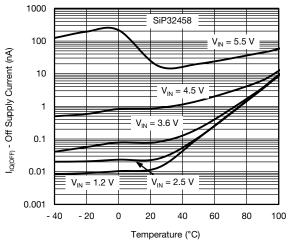


Figure 7 - Off Supply Current vs. Temperature



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#### TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

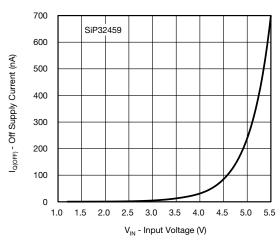


Figure 8 - Off Supply Current vs. Input Voltage

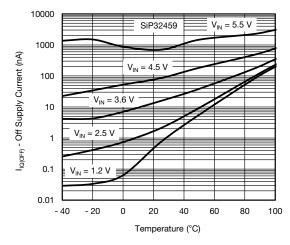


Figure 11 - Off Supply Current vs. Temperature

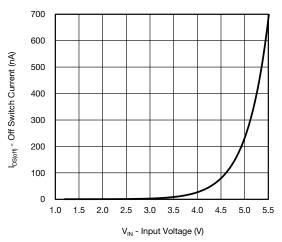


Figure 9 - Off Switch Current vs. Input Voltage

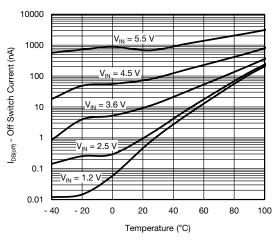


Figure 12 - Off Switch Current vs. Temperature

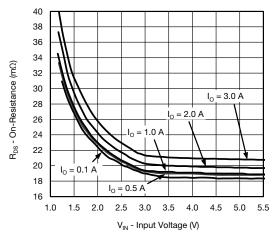


Figure 10 - R<sub>DS(on)</sub> vs. Input Voltage

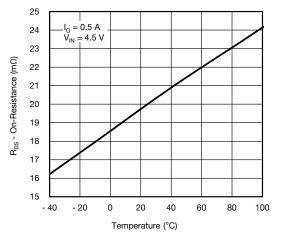


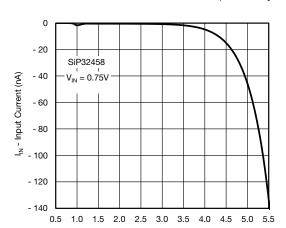
Figure 13 - R<sub>DS(on)</sub> vs. Temperature

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#### TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)



V<sub>OUT</sub> - Output Voltage (V) Figure 14 - Reverse Blocking Current vs. Output Voltage

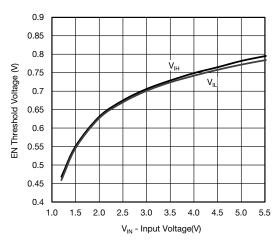


Figure 17 - EN Threshold Voltage vs. Input Voltage

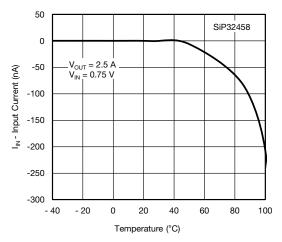


Figure 15 - Reverse Blocking Current vs. Temperature

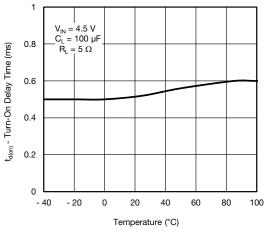


Figure 18 - Turn-On Delay Time vs. Temperature

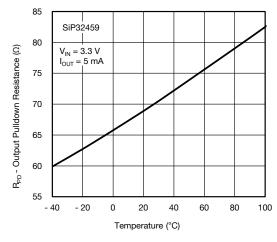


Figure 16 - Output Pulldown Resistance vs. Temperature

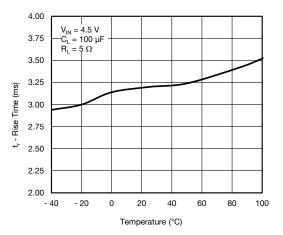


Figure 19 - Rise Time vs. Temperature





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#### TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

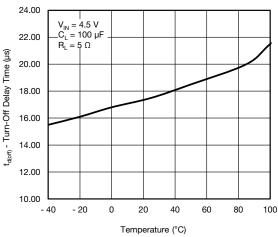


Figure 20 - Turn-Off Delay Time vs. Temperature

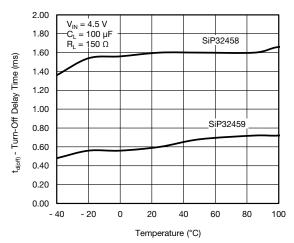


Figure 21 - Turn-Off Delay Time vs. Temperature

#### **TYPICAL WAVEFORMS**

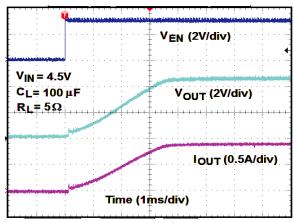


Figure 22 - Turn-On Time  $(V_{IN} = 4.5 \text{ V}, R_L = 5 \Omega, C_L = 100 \mu\text{F})$ 

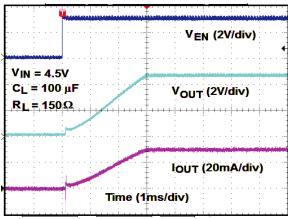


Figure 24 - Turn-On Time  $(V_{IN} = 4.5 \text{ V}, R_{L} = 150 \Omega, C_{L} = 100 \mu\text{F})$ 

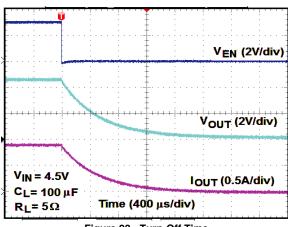


Figure 23 - Turn-Off Time (V<sub>IN</sub> = 4.5 V, R<sub>L</sub> = 5  $\Omega$ , C<sub>L</sub> = 100  $\mu$ F)

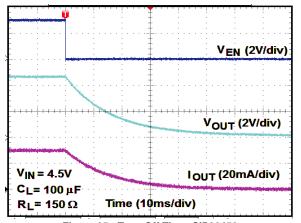


Figure 25 - Turn-Off Time, SiP32458 (V<sub>IN</sub> = 4.5 V, R<sub>L</sub> = 150  $\Omega$ , C<sub>L</sub> = 100  $\mu$ F)

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Datasheet of SIP32458DB-T2-GE1 - IC SW W/CTRL SLEW RATE WCSP6

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### SiP32458, SiP32459

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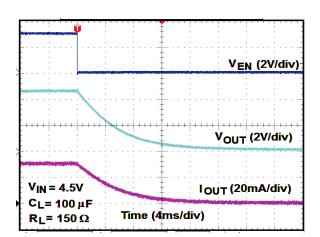


Figure 26 - Turn-Off Time, SiP32459  $(V_{IN}=4.5~V,~R_L=150~\Omega,~C_L=100~\mu F)$ 

#### **DETAILED DESCRIPTION**

SiP32458 and SiP32459 are P-channel power MOSFET designed as high side load switches. They incorporate a negative charge pump at the gate to keep the gate to source voltage high when turned on therefore keep the on resistance low at lower input voltage range. SiP32458 and SiP32459 are designed with slow slew rate to minimize the inrush current during turn on. The SiP32458 has a reverse blocking circuit to prevent the current from going back to the input in case the output voltage is higher than the input voltage. The SiP32459 has an output pulldown resistor to discharge the output capacitance when the device is off.

### **APPLICATION INFORMATION**

#### **Input Capacitor**

While a bypass capacitor on the input is not required, a 4.7  $\mu$ F or larger capacitor for C<sub>IN</sub> is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the input pin to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

#### **Output Capacitor**

A 0.1  $\mu F$  capacitor across  $V_{OUT}$  and GND is recommended to insure proper slew operation. There is inrush current through the output MOSFET and the magnitude of the inrush current depends on the output capacitor, the bigger the COLIT the higher the inrush current. There are no ESR or capacitor type requirement.

#### **Enable**

The EN pin is compatible with CMOS logic voltage levels. It requires at least 0.4 V or below to fully shut down the device and 1 V or above to fully turn on the device. There is a 2.8 M $\Omega$  resistor connected between EN pin and GND pin.



#### **Protection Against Reverse Voltage Condition**

The SiP32458 contains the reverse blocking circuit to keep the output current from flowing back to the input in case the output voltage is higher than the input voltage.

#### **Thermal Considerations**

These devices are designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 3 A as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 110 °C/W) the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependant on the maximum junction temperature,  $T_{J(max.)}$  = 125 °C, the junction-to-ambient thermal resistance,  $\theta_{J-A}$  = 110 °C/W, and the ambient temperature,  $T_A$ , which may be formulaically expressed as:

P (max.) = 
$$\frac{T_J (max.) - T_A}{\theta_{J-A}} = \frac{125 - T_A}{280}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 500 mW.

So long as the load current is below the 3 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the R<sub>DS(ON)</sub> at the ambient temperature.

As an example let us calculate the worst case maximum load current at T<sub>A</sub> = 70 °C. The worst case R<sub>DS(ON)</sub> at 25 °C is 36 m $\Omega$  at V<sub>IN</sub> = 1.5 V. The R<sub>DS(ON)</sub> at 70 °C can be extrapolated from this data using the following formula:

 $R_{DS(ON)}$  (at 70 °C) =  $R_{DS(ON)}$  (at 25 °C) x (1 +  $T_C$  x  $\Delta T$ ) Where T<sub>C</sub> is 2820 ppm/°C. Continuing with the calculation

 $R_{DS(ON)}$  (at 70 °C) = 36 m $\Omega$  x (1 + 0.00282 x (70 °C - 25 °C))  $= 40.5 \text{ m}\Omega$ 

The maximum current limit is then determined by

$$I_{LOAD}$$
 (max.)  $<\sqrt{\frac{P \text{ (max.)}}{R_{DS(ON)}}}$ 

which in this case is 3.5 A. Under the stated input voltage condition, if the 3.5 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 3 A only as listed in the Absolute Maximum Ratings table.

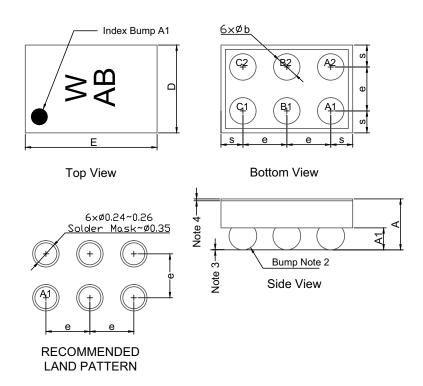




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#### **PACKAGE OUTLINE**

WCSP: 6 Bumps (2 x 3, 0.5 mm Pitch, 250 µm Bump Height, 1 mm x 1.5 mm Die Size)



Dimension		MILLIMETERS <sup>5</sup>		INCHES		
	Min.	Nom.	MAX.	Min.	Nom.	MAX.
Α	0.540	0.572	0.620	0.0212	0.0225	0.0244
A1	0.214	0.250	0.286	0.0084	0.0098	0.0113
b	0.279	0.310	0.372	0.0109	0.0122	0.0146
е	0.500			0.0197		
S	0.230	0.250	0.270	0.0090	0.0098	0.0106
D	0.920	0.960	1.000	0.0362	0.0378	0.0394
E	1.420	1.460	1.500	0.0559	0.0575	0.0591

#### Notes (unless otherwise specified)

- 1. Laser mark on the silicon die back coated with an epoxy film.
- 2. Bumps are SAC396.
- 3. 0.050 max. co-planarity.
- 4. Laminate tape thickness is 0.022 mm.
- 5. Use millimeters as the primary measurement.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63999

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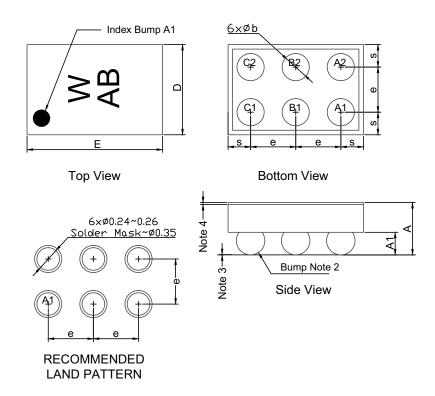
### **Package Information**

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### WCSP6: 6 Bumps

(2 x 3, 0.5 mm pitch, 250 µm bump height, 1 mm x 1.5 mm die size)



	MILLIMETERS (5)			INCHES		
DIMENSION	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	0.540	0.572	0.620	0.0212	0.0225	0.0244
A1	0.214	0.250	0.286	0.0084	0.0098	0.0113
b	0.279	0.310	0.372	0.0109	0.0122	0.0146
е	0.500			0.0197		
S	0.230	0.250	0.270	0.0090	0.0098	0.0106
D	0.920	0.960	1.000	0.0362	0.0378	0.0394
Е	1.420	1.460	1.500	0.0559	0.0575	0.0591

#### Notes (unless otherwise specified)

- (1) Laser mark on the silicon die back coated with an epoxy film.
- (2) Bumps are SAC396.
- (3) 0.050 max. co-planarity.
- (4) Laminate tape thickness is 0.022 mm.
- (5) Use millimeters as the primary measurement.

ECN: S13-1424-Rev. B, 01-Jul-13

DWG: 6011



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